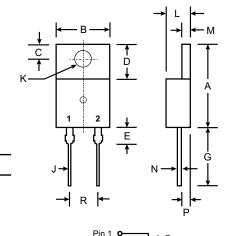


# **MBR870L - MBR8100L**

#### **8.0A SCHOTTKY BARRIER RECTIFIER**

#### **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application
- Plastic Material: UL Flammability Classification Rating 94V-0



Pin 2 **0**-

TO-220AC					
Dim	Min	Max			
Α	14.22	15.88			
В	9.65	10.67			
С	2.54	3.43			
D	5.84	6.86			
E	_	6.35			
G	12.70	14.73			
J	0.51	1.14			
K	3.53∅	4.09∅			
L	3.56	4.83			
М	1.14	1.40			
N	0.30	0.64			
Р	2.03	2.92			
R	4.83	5.33			
All Dimensions in mm					

### **Mechanical Data**

Case: Molded Plastic

Terminals: Plated Leads Solderable per

MIL-STD-202, Method 208
Polarity: See Diagram

Weight: 2.24 grams (approx.)

Mounting Position: AnyMarking: Type Number

## Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	MBR 870L	MBR 880L	MBR 890L	MBR 8100L	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		70	80	90	100	٧
RMS Reverse Voltage		49	56	63	70	٧
Average Rectified Output Current (Note 1) @ T <sub>C</sub> = 125°C		8.0				А
Non-Repetitive Peak Forward Surge Current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		230			А	
Repetitive Peak Forward Surge Current @ $t \le 5.0 \mu s$		850			Α	
Forward Voltage Drop @ I <sub>F</sub> = 8.0A, T <sub>C</sub> = 25°C @ I <sub>F</sub> = 8.0A, T <sub>C</sub> = 125°C		0.72 0.58			٧	
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		0.55 7.0				mA
Typical Junction Capacitance (Note 2)		350			pF	
Typical Thermal Resistance Junction to Case (Note 1)		2.0				K/W
Voltage Rate of Change (Rated V <sub>R</sub> )		10,000				V/µs
Operating and Storage Temperature Range		-55 to +175			°C	

Notes: 1. Thermal resistance junction to case mounted on heatsink.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

